# 2SB0951, 2SB0951A (2SB951, 2SB951A)

### Silicon PNP epitaxial planar type Darlington

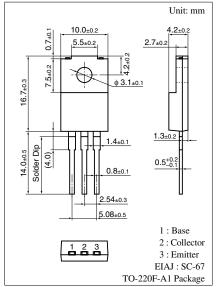
For midium-speed switching Complementary to 2SD1277 and 2SD1277A

#### Features

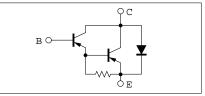
- $\bullet$  High forward current transfer ratio  $h_{FE}$
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

Parameter		Symbol	Rating	Unit				
Collector to base	2SB0951	V <sub>CBO</sub>	-60	V				
voltage	2SB0951A		-80					
Collector to	2SB0951	V <sub>CEO</sub>	-60	V				
emitter voltage	2SB0951A		-80					
Emitter to base voltage		V <sub>EBO</sub>	-7	V				
Peak collector current		I <sub>CP</sub>	-12	А				
Collector current		I <sub>C</sub>	-8	А				
Collector power	$T_C = 25^{\circ}C$	P <sub>C</sub>	45	W				
dissipation	$T_a = 25^{\circ}C$		2					
Junction temperature		Tj	150	°C				
Storage temperature		T <sub>stg</sub>	-55 to +150	°C				

#### Absolute Maximum Ratings $T_c = 25^{\circ}C$



#### Internal Connection



#### Electrical Characteristics $T_C = 25^{\circ}C$

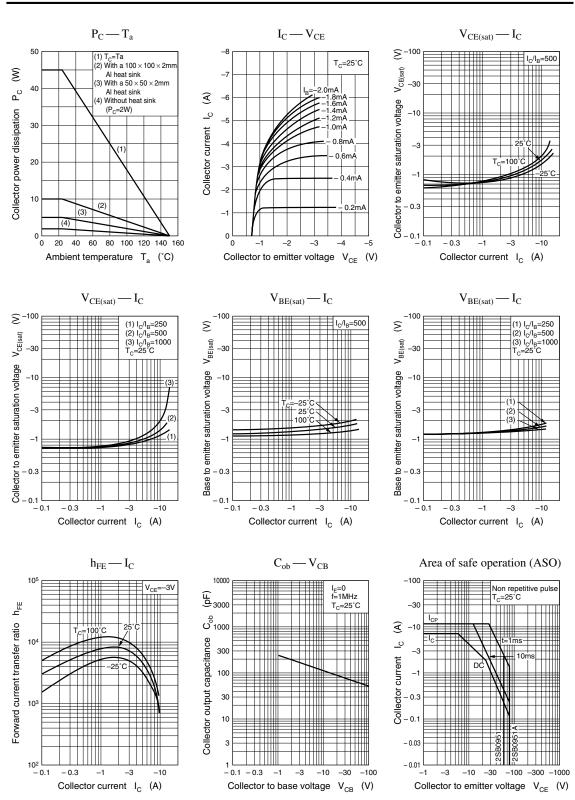
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SB0951	$I_{CBO}$ $V_{CB} = -60 \text{ V}, I_E = 0$				-100	μΑ
current	2SB0951A		$V_{CB} = -80 \text{ V}, I_E = 0$			-100	
Emitter cutoff current		I <sub>EBO</sub>	$V_{EB} = -7 V, I_C = 0$			-2	mA
Collector to emitter	2SB0951	V <sub>CEO</sub>	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = 0$	-60			V
voltage	2SB0951A			-80			
Forward current transfer ratio		h <sub>FE1</sub> *	$V_{CE} = -3 V, I_C = -4 A$	2 000		10 000	
		h <sub>FE2</sub>	$V_{CE} = -3 V, I_C = -8 A$	500			
Collector to emitter saturation voltage		V <sub>CE(sat)</sub>	$I_{\rm C} = -4$ A, $I_{\rm B} = -8$ mA			-1.5	V
Base to emitter saturation voltage		V <sub>BE(sat)</sub>	$I_{\rm C} = -4$ A, $I_{\rm B} = -8$ mA			-2	V
Transition frequency		$f_{T}$	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time		t <sub>on</sub>	$I_{C} = -4 \text{ A}, I_{B1} = -8 \text{ mA}, I_{B2} = 8 \text{ mA},$		0.5		μs
Storage time		t <sub>stg</sub>	$V_{\rm CC} = -50 \text{ V}$		2		μs
Fall time		t <sub>f</sub>	1		1		μs

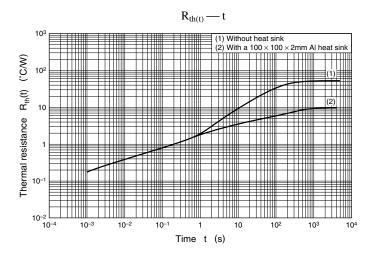
Note) \*: Rank classification

 Rank
 Q
 P

 h<sub>FE1</sub>
 2 000 to 5 000
 4 000 to 10 000

Note.) The Part numbers in the Parenthesis show conventional part number.





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